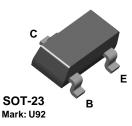




BSR17A



NPN General Purpose Amplifier

This device is designed as a general purpose amplifier and switch. The useful dynamic range extends to 100 mA as a switch and to 100 MHz as an amplifier. Sourced from Process 23.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	40	V
V _{CBO}	Collector-Base Voltage	60	V
V _{EBO}	Emitter-Base Voltage	6.0	V
I _C	Collector Current - Continuous	200	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES: 1) These ratings are based on a maximum junction temperature of 150 degrees C. 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Мах	Units
		*BSR17A	
PD	Total Device Dissipation	350	mW
	Derate above 25°C	2.8	mW/°C
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	357	°C/W

*Device mounted on FR-4 PCB 40 mm X 40 mm X 1.5 mm.

NPN General Purpose Amplifier (continued)

Symbol	Parameter	Test Conditions	Min	Max	Units
					1
OFF CHA	RACTERISTICS				
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	$I_{C} = 10 \ \mu A, I_{B} = 0$	60		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 1.0 \text{ mA}, I_{\rm E} = 0$	40		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{E} = 10 \ \mu A, I_{C} = 0$	6.0		V
I _{СВО}	Collector-Cutoff Current	$V_{CB} = 30 \text{ V}, \text{T}_{\text{A}} = 150^{\circ}\text{C}$		5.0	μΑ
ICEX	Collector-Cutoff Current	$V_{CE} = 30 \text{ V}, \text{ V}_{EB} = 3.0 \text{ V}$		50	nA
I _{BEX}	Reverse Base Current	$V_{CE} = 30 \text{ V}, \text{ V}_{EB} = 3.0 \text{ V}$		50	nA
	ACTERISTICS				
	DC Current Gain	I _C = 0.1 mA, V _{CE} = 1.0 V	40		
IFE		$I_{\rm C} = 0.1$ mA, $V_{\rm CE} = 1.0$ V $I_{\rm C} = 1.0$ mA, $V_{\rm CE} = 1.0$ V	70		
		$I_{\rm C} = 10 \text{ mA}, V_{\rm CE} = 1.0 \text{ V}$	100	300	
		$I_{C} = 50 \text{ mA}, V_{CE} = 1.0 \text{ V}$	60		
		$I_{\rm C} = 100 \text{ mA}, V_{\rm CE} = 1.0 \text{ V}$	30		
V _{CE(sat)}	Collector-Emitter Saturation Voltage*	$I_{C} = 10 \text{ mA}, I_{B} = 1.0 \text{ mA}$ $I_{C} = 50 \text{ mA}, I_{B} = 5.0 \text{ mA}$		0.2 0.3	
V _{BE(sat)}	Base-Emitter Saturation Voltage*	$I_{\rm C} = 30 \text{ mA}, I_{\rm B} = 3.0 \text{ mA}$	0.65	0.3	V V
· DE(Sat)	5	$I_{\rm C} = 50 \text{ mA}, I_{\rm B} = 5.0 \text{ mA}$		0.95	V
	IGNAL CHARACTERISTICS				
	Transition Frequency	$I_{\rm C} = 20 \text{ mA}, V_{\rm CE} = 20 \text{ V},$	300		MHz
f _T	Transition Frequency	$f_{c} = 20 \text{ MA}, v_{ce} = 20 \text{ v},$ f = 100 MHz	300		IVITIZ
C _{cb}	Collector-Base Capacitance	$V_{CB} = 5.0 \text{ V}, I_E = 0, f = 1.0 \text{ MHz}$		4.0	pF
C _{eb}	Emitter-Base Capacitance	$V_{EB} = 0.5 \text{ V}, I_C = 0, f = 1.0 \text{ MHz}$		8.0	pF
h _{ie}	Input Impedance	V _{CE} = 10 V,I _C = 1.0 mA,f=1.0 kHz	1.0	10	kΩ
h _{fe}	Small-Signal Current Gain	V _{CE} = 10 V,I _C = 1.0 mA,f=1.0 kHz	100	400	
h _{oe}	Output Admittance	V _{CE} = 10 V,I _C = 1.0 mA,f=1.0 kHz	1.0	40	μS
SWITCHI	NG CHARACTERISTICS			1	
t _d	Delay Time	$I_{C} = 10 \text{ mA}, I_{B1} = 1.0 \text{ mA}, V_{EB} = 0.5 \text{ V}$		35	ns
tr	Rise Time			35	ns
t _s	Storage Time	$I_{\rm C}$ = 10 mA, $I_{\rm Bon}$ = $I_{\rm Boff}$ = 1.0 mA		200	ns
t _f	Fall Time			50	ns

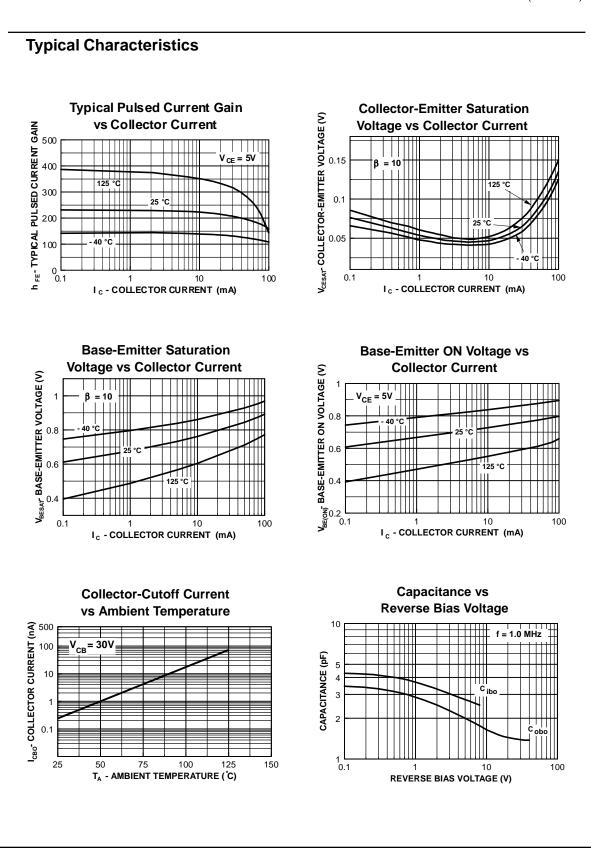
Spice Model

NPN (Is=6.734f Xti=3 Eg=1.11 Vaf=74.03 Bf=416.4 Ne=1.259 Ise=6.734 Ikf=66.78m Xtb=1.5 Br=.7371 Nc=2 Isc=0 Ikr=0 Rc=1 Cjc=3.638p Mjc=.3085 Vjc=.75 Fc=.5 Cje=4.493p Mje=.2593 Vje=.75 Tr=239.5n Tf=301.2p Itf=.4 Vtf=4 Xtf=2 Rb=10)

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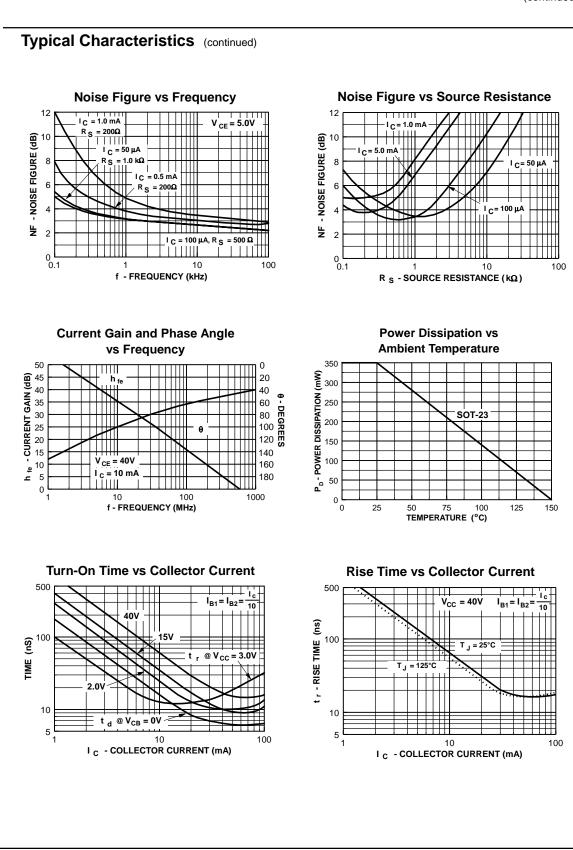
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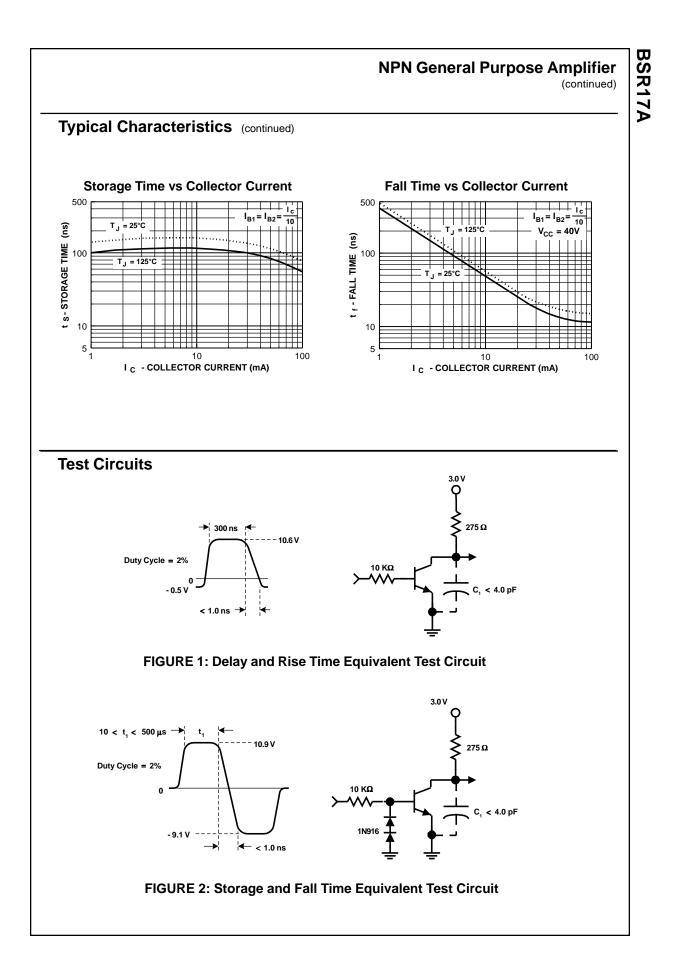
NPN General Purpose Amplifier (continued)



NPN General Purpose Amplifier (continued)

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